# NSN 5961-01-014-1061

Transistor - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.340 inches

### **Overall Height:**

0.340 inches

**Overall Width:** 

0.620 inches

#### **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

8.00 amperes all primaries

#### **Power Rating Per Characteristic:**

14.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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